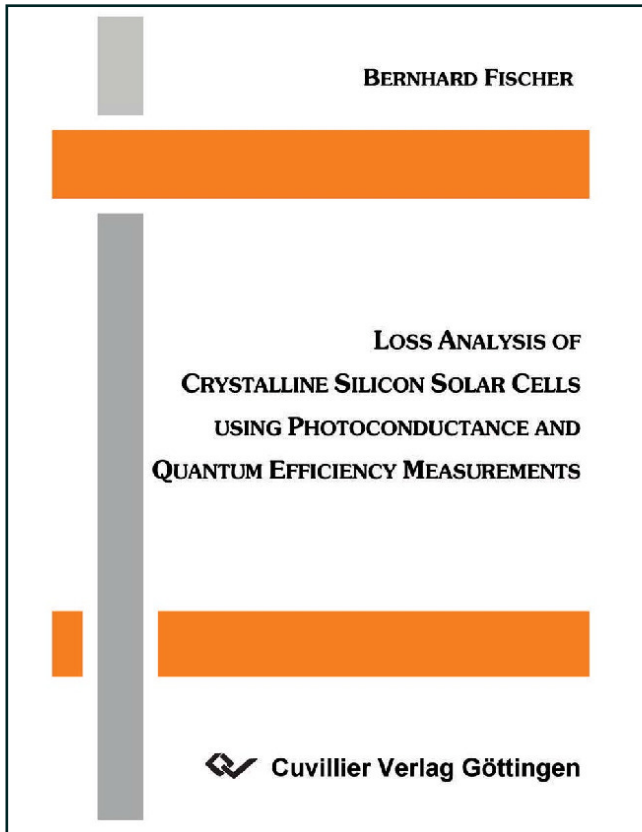




Bernhard Fischer (Autor)

Loss Analysis of Crystalline Silicon Solar Cells using Photoconductance and Quantum Efficiency Measurements



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